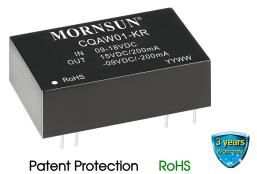


4.8W, Wide input, isolated & regulated dual output, IGBT dedicated DC-DC converter



FEATURES

- Wide input voltage range: 2:1
- High efficiency up to 85%
- Isolation voltage: 3kVDC
- Short Circuit Protection
- Output Over-voltage Protection
- Operating temperature range:-40℃ to +85℃
- International standard pin-out
- Regulated Converter for IGBT driver
- The production process meet IATF16949 system requirements

CQAW01-KR is DC-DC converters for IGBT drivers, offer 4.8W of output, with output over-voltage protection and short-circuit protection. General application includes:

- 1.General inverter
- 2.AC servo drive system
- 3.Electric welding machine
- 4.Uninterruptible power supply (UPS)

Selection	Guide					
	In	out	Ou	tput	Efficiency	Max.
Part No.	Input Voltage (VDC)	Input Current (mA,Typ) Full Load/No Load	Output Voltage (VDC)+Vo/-Vo	Output Current (mA)+lo/-lo	(%,Typ.) @ Full Load	Capacitive Load* (µF)
CQAW01-KR	12(9-18)	471/16	+15/-9	±200/±10	85	1000
Note:*For each	output.					

Input Specification	าร				
Item	Operating Conditions	Min.	Тур.	Max.	Unit
Surge Voltage Input	12VDC input	-0.7		25	VDC
Starting Voltage	12VDC input	-	-	9	VDC
Input Filter			π	Filter	'
Hot Plug			Unav	ailable	

Item	Operating Conditions	Min.	Тур.	Max.	Unit
Output Power		0.24		4.8	W
Outro de Malderese A a a company	Main output(+15V output)		±1	±2	
Output Voltage Accuracy	Supplement output(-9V output)		±3	±5	0,
Line Regulation	gulation Full load, the input voltage is from low to high		±0.2	±0.5	%
Load Regulation	5%-100% load		±0.5	±1	
Transient Recovery Time	OFW In and about the state of		300	500	μs
Transient Response time	25% load step change		±3	±5	%
Temperature Coefficient	100% load			±0.03	%/℃
Ripple & Noise*	20MHz bandwidth		100	200	mVp-p
Output Over-voltage Protection	land to the control of	110	120	140	% Vo
Output Short Circuit Protection	Input voltage range		Continuous,	self-recove	ry

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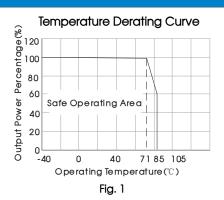


General Specification	o <mark>ns</mark>				
Item	Operating Conditions	Min.	Тур.	Max.	Unit
Insulation Voltage	Input-output, with the test time of 1 minute and the leak current lower than 1mA	3000			VDC
Insulation Resistance	Input-output, isolation voltage 500VDC	1000			M Ω
Isolation Capacitance	Input-output, 100kHz/0.1V		100		pF
Operating Temperature	Power derating≥71°C, (see Fig. 1)	-40		85	
Storage Temperature		-55	-	125	
Pin Welding Resistance Temperature	Welding spot is 1.5mm away from the casing, 10 seconds			300	_ ℃
Casing Temperature Rise	Ta=25℃		30	40	
Storage Humidity	Non-condensing	5		95	%RH
Switching Frequency	100% load, nominal input voltage		300		kHz
MTBF	MIL-HDFK-217F@25℃	1000	-	_	k hours

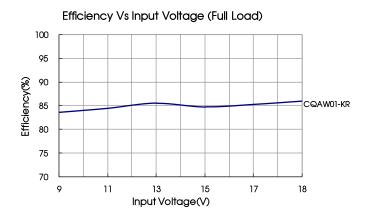
Physical Specifications	
Casing Material	Black flame-retardant and heat-resistant plastic (UL94 V-0)
Dimensions	31.60*20.30*10.20 mm
Weight	14g (Typ.)
Cooling Method	Free air convection

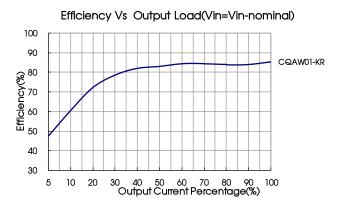
EMC	Specifications Specifications			
EMI	CE	CISPR32/EN55032	CLASS A (see Fig. 4-2) for recommended circuit)	
CIVII	RE	CISPR32/EN55032	CLASS A (see Fig. 4-2) for recommended circuit)	
	ESD	IEC/EN61000-4-2	Contact ±4kV	perf. Criteria B
	RS	IEC/EN61000-4-3	10V/m	perf. Criteria A
	EFT	IEC/EN61000-4-4	±2kV (see Fig. 4-① for recommended circuit)	perf. Criteria B
EMS	Surge	IEC/EN61000-4-5	±2kV (see Fig. 4-① for recommended circuit)	perf. Criteria B
	CS	IEC/EN61000-4-6	3 Vr.m.s	perf. Criteria A
	Voltage dips, short interruptions and voltage variations immunity	IEC/EN61000-4-29	0%, 70%	perf. Criteria B

Product Characteristic Curve







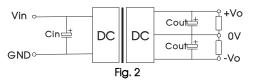


Design Reference

1. Typical application

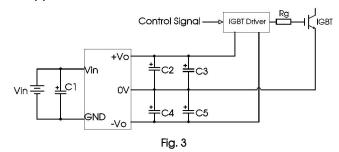
It is tested according to the recommended circuit (see Fig. 2) before delivery.

If it is required to further reduce input and output ripple, properly increase the input & output of additional capacitors Cin and Cout or select capacitors of low equivalent impedance provided that the capacitance is no larger than the max, capacitive load of the product.



Vin	12V
Cin	100µF
Cout	100µF

2. Application circuit



C1	100uF/63V(Electrolytic capacitor)
C2 /C4	100uF/35V(Electrolytic capacitor)
C3/C5	10uF/25V(Ceramic capacitor)

3. EMC solution-recommended circuit

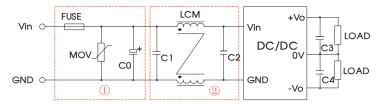


Fig. 4

CQAW01-KR

FUSE Choose according to practical input current

MOV \$14k25

C0 680µF/25V

C1, C2 4.7µF/50V

C3, C4 Refer to the Cout in Fig.2

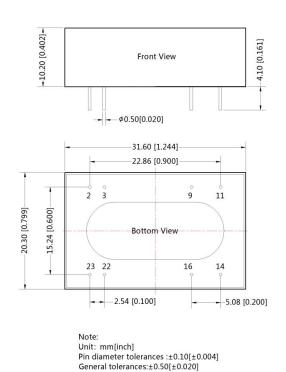
LCM 1mH

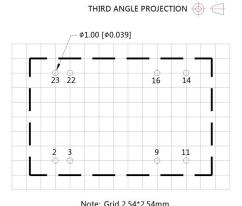
4. It is not allowed to connect modules output in parallel to enlarge the power



5. For more information please find the application notes on www.mornsun-power.com

Dimensions and Recommended Layout





Pin-Out	
Pin	Mark
2,3	GND
9	0V
11	-Vo
14	+Vo
16	0V
22,23	Vin

Notes:

- Packaging information please refer to Product Packing Information which can be downloaded from <u>www.mornsun-power.com</u>. Packing bag number: 58210008;
- 2. The lead connecting the power supply module and IGBT driver should be as short as possible during use;
- 3. The output filtering capacitor should be as close as possible to the power supply module and IGBT driver;
- 4. The peak of the IGBT driver gate drive current is high, so low internal resistance electrolytic capacitor is recommended to be used for the power supply module output filter capacitor;
- 5. The average output power of the driver must be lower than that of the power supply module;
- 6. Consider fixing with glue near the module if being used in vibration occasion;
- 7. The max. capacitive load should be tested within the input voltage range and under full load conditions;
- 8. Unless otherwise specified, data in this datasheet should be tested under the conditions of Ta=25° C, humidity<75% when inputting nominal voltage and outputting rated load;
- All index testing methods in this datasheet are based on our company corporate standards;
- 10. The performance indexes of the product models listed in this manual are as above, but some indexes of non-standard model products will exceed the above-mentioned requirements, and please directly contact our technicians for specific information;
- 11. We can provide product customization service;
- 12. Products are related to laws and regulations: see "Features" and "EMC";
- 13. Our products shall be classified according to ISO14001 and related environmental laws and regulations, and shall be handled by qualified units

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